

MOS FIELD EFFECT TRANSISTOR

2SK3435

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The 2SK3435 is N-channel MOS Field Effect Transistor designed for high current switching applications.

FEATURES

• Super low on-state resistance:

 $R_{DS(on)1} = 14 \text{ m}\Omega$ MAX. (Vgs = 10 V, ID = 40 A)

- \bigstar RDS(on)2 = 22 m Ω MAX. (VGS = 4.0 V, ID = 40 A)
- ★ Low Ciss: Ciss = 3200 pF TYP.
 - Built-in gate protection diode

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

	Drain to Source Voltage	Voss	60	V
	Gate to Source Voltage	Vgss	±20	V
	Drain Current (DC)	I _{D(DC)}	±80	Α
	Drain Current (pulse) Note1	D(pulse)	±320	Α
*	Total Power Dissipation (Tc = 25°C)	P_T	84	W
	Total Power Dissipation ($T_A = 25^{\circ}C$)	PT	1.5	W
	Channel Temperature	Tch	150	°C
	Storage Temperature	T_{stg}	-55 to +150	°C
*	Single Avalanche Current Note2	Ias	31	Α
*	Single Avalanche Energy Note2	Eas	96	mJ

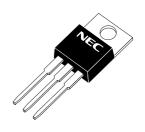
Notes 1. PW \leq 10 μ s, Duty cycle \leq 1 %

2. Starting T_{ch} = 25 °C, R_G = 25 Ω , V_{GS} = 20 V \rightarrow 0 V

ORDERING INFORMATION

PART NUMBER	PACKAGE		
2SK3435	TO-220AB		
2SK3435-S	TO-262		
2SK3435-Z	TO-220SMD		

(TO-220AB)



(TO-262)



(TO-220SMD)



THERMAL RESISTANCE

\star	Channel to Case	Rth(ch-C)	1.49	°C/W
	Channel to Ambient	Rth(ch-A)	83.3	°C/W

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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

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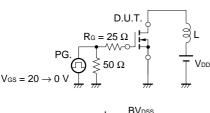
10 %

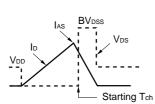


查记记录记名记名记号CHARACTERISTICS (TA = 25 °C)

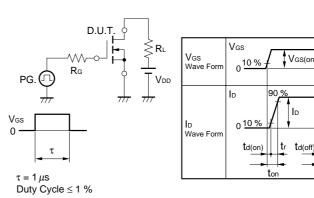
	CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
	Drain to Source On-state Resistance	RDS(on)1	Vgs = 10 V, ID = 40 A		11	14	mΩ
*		RDS(on)2	Vgs = 4.0 V, ID = 40 A		16	22	mΩ
	Gate to Source Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.5	2.0	2.5	V
*	Forward Transfer Admittance	y _{fs}	V _{DS} = 10 V, I _D = 40 A	21	43		S
	Drain Leakage Current	Ipss	V _{DS} = 60 V, V _{GS} = 0 V			10	μΑ
	Gate to Source Leakage Current	Igss	Vgs = ±20 V, Vps = 0 V			±10	μΑ
*	Input Capacitance	Ciss	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz		3200		pF
	Output Capacitance	Coss			520		pF
	Reverse Transfer Capacitance	Crss			260		pF
	Turn-on Delay Time	td(on)	ID = 40 A, VGS(on) = 10 V, VDD = 30 V,		80		ns
*	Rise Time	tr	R _G = 10 Ω		1200		ns
	Turn-off Delay Time	td(off)			200		ns
	Fall Time	t f			350		ns
*	Total Gate Charge	Q _G	ID = 80 A , VDD = 48 V, VGS = 10 V		60		nC
*	Gate to Source Charge	Qgs			10		nC
*	Gate to Drain Charge	Q _{GD}			16		nC
	Body Diode Forward Voltage	V _{F(S-D)}	IF = 80 A, VGS = 0 V		1.0		V
*	Reverse Recovery Time	trr	IF = 80 A, VGS = 0 V,		46		ns
*	Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		66		nC

TEST CIRCUIT 1 AVALANCHE CAPABILITY

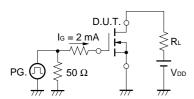




TEST CIRCUIT 2 SWITCHING TIME



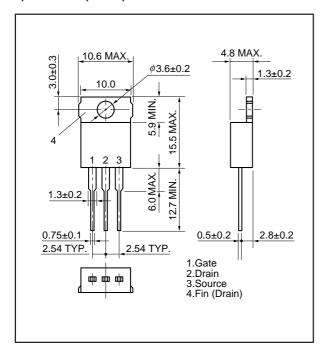
TEST CIRCUIT 3 GATE CHARGE



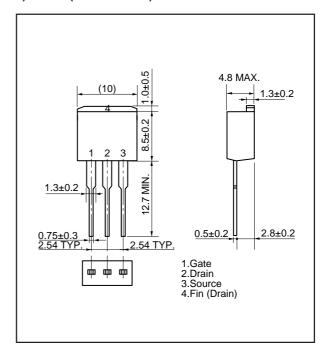


章ACKAGE DRAWINGS (Unit: mm)

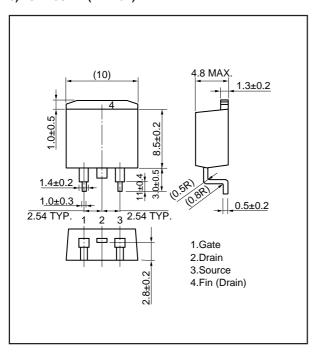
1) TO-220AB (MP-25)



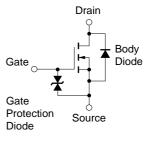
2) TO-262 (MP-25 Fin Cut)



3) TO-220SMD (MP-25Z)



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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